

# TIP131, TIP132 (NPN), TIP137 (PNP)



**ON Semiconductor®**

<http://onsemi.com>

## Darlington Complementary Silicon Power Transistors

Designed for general-purpose amplifier and low-speed switching applications.

### Features

- High DC Current Gain –  
 $h_{FE} = 2500$  (Typ) @  $I_C$   
 $= 4.0$  Adc
- Collector–Emitter Sustaining Voltage – @ 30 mAdc  
 $V_{CEO(sus)} = 80$  Vdc (Min) – TIP131  
 $= 100$  Vdc (Min) – TIP132, TIP137
- Low Collector–Emitter Saturation Voltage –  
 $V_{CE(sat)} = 2.0$  Vdc (Max) @  $I_C = 4.0$  Adc  
 $= 3.0$  Vdc (Max) @  $I_C = 6.0$  Adc
- Monolithic Construction with Built–In Base–Emitter Shunt Resistors
- Pb–Free Packages are Available\*

### MAXIMUM RATINGS

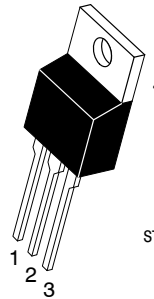
Rating	Symbol	TIP131	TIP132 TIP137	Unit
Collector–Emitter Voltage	$V_{CEO}$	80	100	Vdc
Collector–Base Voltage	$V_{CB}$	80	100	Vdc
Emitter–Base Voltage	$V_{EB}$	5.0		Vdc
Collector Current – Continuous Peak	$I_C$	8.0 12		Adc
Base Current	$I_B$	300		mAdc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	$P_D$	70		W
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	$P_D$	2.0		W
Operating and Storage Junction, Temperature Range	$T_J, T_{stg}$	–65 to +150		$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	1.78	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	63.5	$^\circ\text{C}/\text{W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## DARLINGTON 8 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 80–100 VOLTS, 70 WATTS



### MARKING DIAGRAM



**TO-220AB  
CASE 221A  
STYLE 1**

STYLE 1:  
PIN 1. BASE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR

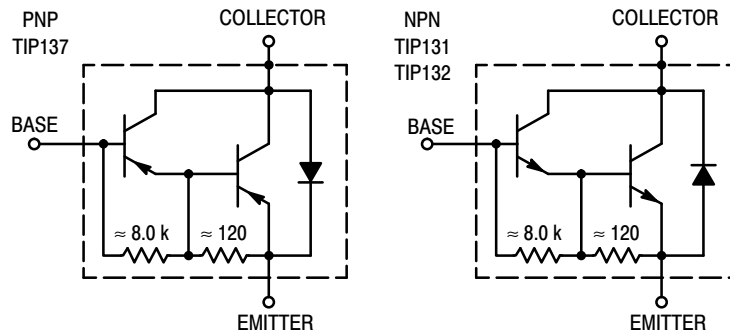
TIP13x = Device Code  
 x = 1, 2, or 7  
 A = Assembly Location  
 Y = Year  
 WW = Work Week  
 G = Pb–Free Package

### ORDERING INFORMATION

Device	Package	Shipping
TIP131	TO–220	50 Units/Rail
TIP131G	TO–220 (Pb–Free)	50 Units/Rail
TIP132	TO–220	50 Units/Rail
TIP132G	TO–220 (Pb–Free)	50 Units/Rail
TIP137	TO–220	50 Units/Rail
TIP137G	TO–220 (Pb–Free)	50 Units/Rail

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## TIP131, TIP132 (NPN), TIP137 (PNP)



**Figure 1. Darlington Circuit Schematic**

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector–Emitter Sustaining Voltage (Note 1) ( $I_C = 30 \text{ mAdc}$ , $I_B = 0$ )	$V_{CE(sus)}$	80 100	– –	Vdc
Collector Cutoff Current ( $V_{CE} = 40 \text{ Vdc}$ , $I_B = 0$ ) ( $V_{CE} = 50 \text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	– –	0.5 0.5	mAdc
Collector Cutoff Current ( $V_{CB} = 80 \text{ Vdc}$ , $I_E = 0$ ) ( $V_{CB} = 100 \text{ Vdc}$ , $I_E = 0$ )	$I_{CBO}$	– –	0.2 0.2	mAdc
Emitter Cutoff Current ( $V_{BE} = 5.0 \text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	–	5.0	mAdc
<b>ON CHARACTERISTICS (Note 1)</b>				
DC Current Gain ( $I_C = 1.0 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$ ) ( $I_C = 4.0 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$ )	$h_{FE}$	500 1000	– 15000	–
Collector–Emitter Saturation Voltage ( $I_C = 4.0 \text{ Adc}$ , $I_B = 16 \text{ mAdc}$ ) ( $I_C = 6.0 \text{ Adc}$ , $I_B = 30 \text{ mAdc}$ )	$V_{CE(sat)}$	– –	2.0 3.0	Vdc
Base–Emitter On Voltage ( $I_C = 4.0 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$ )	$V_{BE(on)}$	–	2.5	Vdc

1. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

# TIP131, TIP132 (NPN), TIP137 (PNP)

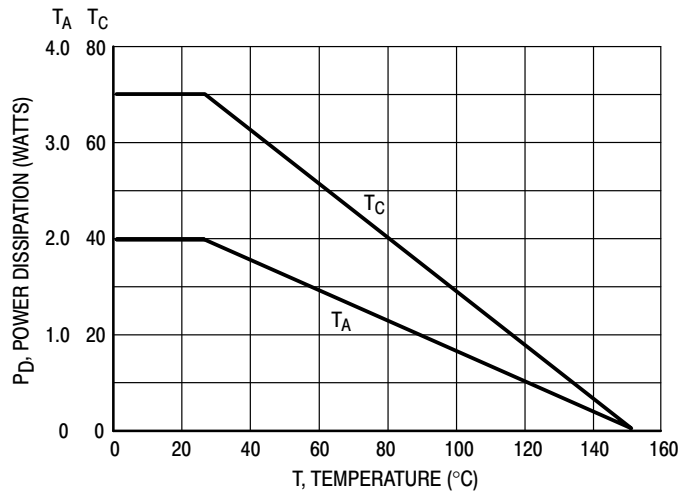


Figure 2. Power Derating

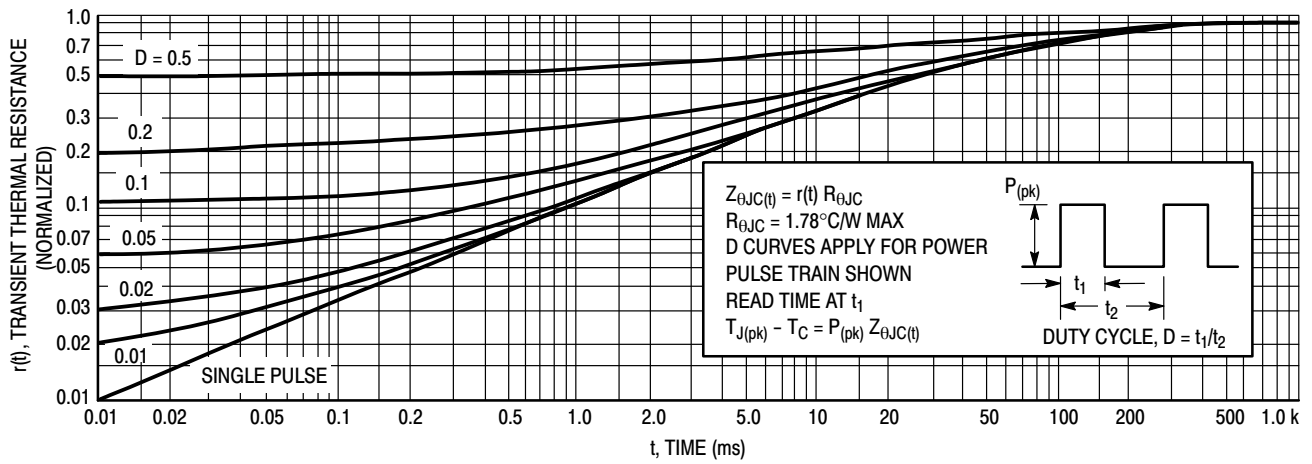
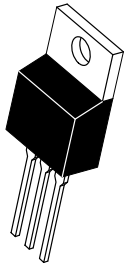


Figure 3. Thermal Response

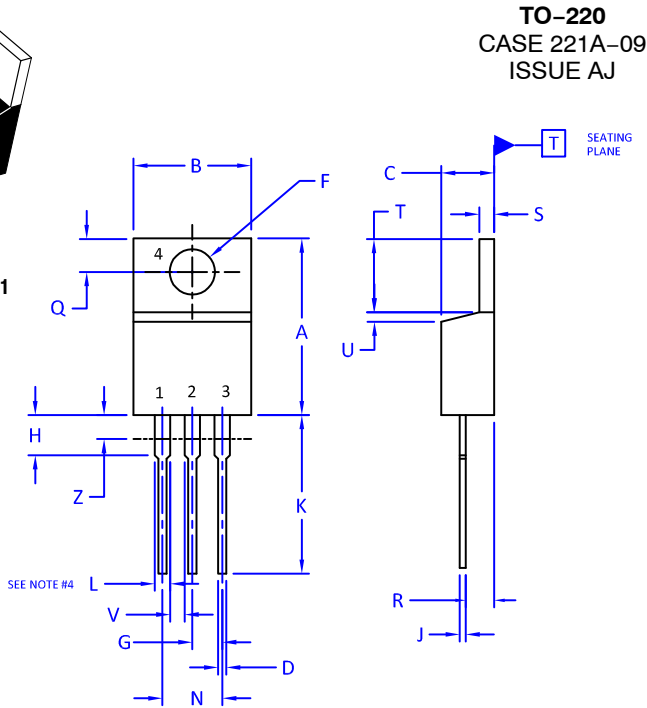
# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

ON Semiconductor®



SCALE 1:1



### TO-220 CASE 221A-09 ISSUE AJ

DATE 05 NOV 2019

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 2009.
2. CONTROLLING DIMENSION: INCHES
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.
4. MAX WIDTH FOR F102 DEVICE = 1.35MM

DIM	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.570	0.620	14.48	15.75
B	0.380	0.415	9.66	10.53
C	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.60	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.41
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

**STYLE 1:**

- PIN 1. BASE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR

**STYLE 2:**

- PIN 1. BASE
- 2. EMITTER
- 3. COLLECTOR
- 4. EMITTER

**STYLE 3:**

- PIN 1. CATHODE
- 2. ANODE
- 3. GATE
- 4. ANODE

**STYLE 4:**

- PIN 1. MAIN TERMINAL 1
- 2. MAIN TERMINAL 2
- 3. GATE
- 4. MAIN TERMINAL 2

**STYLE 5:**

- PIN 1. GATE
- 2. DRAIN
- 3. SOURCE
- 4. DRAIN

**STYLE 6:**

- PIN 1. ANODE
- 2. CATHODE
- 3. ANODE
- 4. CATHODE

**STYLE 7:**

- PIN 1. CATHODE
- 2. ANODE
- 3. CATHODE
- 4. ANODE

**STYLE 8:**

- PIN 1. CATHODE
- 2. ANODE
- 3. EXTERNAL TRIP/DELAY
- 4. ANODE

**STYLE 9:**

- PIN 1. GATE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR

**STYLE 10:**

- PIN 1. GATE
- 2. SOURCE
- 3. DRAIN
- 4. SOURCE

**STYLE 11:**

- PIN 1. DRAIN
- 2. SOURCE
- 3. GATE
- 4. SOURCE

**STYLE 12:**

- PIN 1. MAIN TERMINAL 1
- 2. MAIN TERMINAL 2
- 3. GATE
- 4. NOT CONNECTED

<b>DOCUMENT NUMBER:</b>	<b>98ASB42148B</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>TO-220</b>	<b>PAGE 1 OF 1</b>

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Email Requests to: [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

ON Semiconductor Website: [www.onsemi.com](http://www.onsemi.com)

### TECHNICAL SUPPORT

North American Technical Support:  
Voice Mail: 1 800-282-9855 Toll Free USA/Canada  
Phone: 011 421 33 790 2910

### Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative